## SiPM workshop: from fundamental research to industrial applications



Contribution ID: 35

Type: Oral presentation

## SiPMs characteristics after very high Radiation at low Temperature for the SLHC CMS PHASE II upgrade

Wednesday, 2 October 2019 18:20 (20 minutes)

The design of the CMS phase II upgrade for the SHLC uses SiPMs for the Barrel Timing Layer (BTL) and the Behind HCAL detector (BH). In both sub-detectors the SiPMs will see a 1 MeV Equivalent dose of around  $10E14 \, \text{n/cm2}$ . To lower the noise in the SiPMs the design is to run at a low temperature of -30C .

Different samples from two manufactures of SiPMs were radiated up to a very high total dose of 4\*10E14 at the TRIGA reactor at the JSI in Slovenia.

We compare samples of 4 different wafers with different internal electric field from FBK-irst (Italy). We study the noise vs temperature down to -40C after different irradiations. We also report on PDE change and breakdown voltage shifts after the highest neutron doses.

**Primary author:** HEERING, Adriaan (University of Notre Dame (US))

Co-authors: Dr MUSIENKO, Yuri; Prof. WAYNE, Mitchell (University of Notre Dame)

**Presenter:** HEERING, Adriaan (University of Notre Dame (US)) **Session Classification:** High-energy and nuclear physics